
	<h2>SIA910EDJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA910EDJ-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 12V 4.5A SC-70-6</p> <p>Datenblätter:  SIA910EDJ-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 23672 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA910EDJ-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 12V 4.5A SC-70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	23672 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	7.8W
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	12V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A
Rds On (Max) @ Id, Vgs	28 mOhm @ 5.2A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	455pF @ 6V
Verpackung	Tape & Reel (TR)

















































SIA910EDJ-T1-GE3 ist neu im Original, Suche SIA910EDJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA910EDJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA910EDJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIA910EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 12V 4.5A SC-70-6</p>	 <p>SIA907EDJT VISHAY SIA907EDJT VISHAY</p>	 <p>SIA907EDJT-T4-GE3 VISHAY SIA907EDJT-T4-GE3 VISHAY</p>	 <p>SIA911ADJ-T5-GE3 VISHAY SIA911ADJ-T5-GE3 VISHAY</p>
 <p>SIA907EDJT-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 4.5A SC-70-6L</p>	 <p>SIA911ADJ-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 4.5A SC70-6</p>	 <p>SIA911ADJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 4.5A SC70-6</p>	 <p>SIA911DJ-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 4.5A SC70-6</p>

heiße Teile

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|  SIA519EDJ-T1-GE3 |  SIA519EDJ-T1-GE3 |  SIA533EDJ-T1-GE3 |  SIA533EDJ-T1-GE3 |  SIA778DJ-T1-GE3 |
|  SIA778DJ-T1-GE3 |  SIA811ADJ-T1-GE3 |  SIA811ADJ-T1-GE3 |  SIA811DJ-T1 |  SIA811DJ-T1-E3 |
|  SIA811DJ-T1-E3 |  SIA811DJ-T1-GE3 |  SIA811DJ-T1-GE3 |  SIA813DJ-T1-GE3 |  SIA813DJ-T1-GE3 |
|  SIA814DJ-T1-GE3 |  SIA814DJ-T1-GE3 |  SIA906EDJ-T1-GE3 |  SIA906EDJ-T1-GE3 |  SIA906EDJ-T4-GE3 |
|  SIA907EDJT |  SIA907EDJT-T1-GE3 |  SIA907EDJT-T1-GE3 |  SIA907EDJT-T4-GE3 |  SIA910EDJ-T1-GE3 |
|  SIA911ADJ-T1-GE3 |  SIA911ADJ-T1-GE3 |  SIA911ADJ-T5-GE3 |  SIA911DJ-T1-E3 |  SIA911DJ-T1-E3 |
|  SIA911DJ-T1-GE3 |  SIA911DJ-T1-GE3 |  SIA911DJ-T5-GE3 |  SIA911EDJ-T1-GE3 |  SIA911EDJ-T1-GE3 |
|  SIA912DJ |  SIA912DJ-T1-GE3 |  SIA912DJ-T1-GE3 |  SIA913ADJ-T1-GE3 |  SIA913ADJ-T1-GE3 |
|  SIA913DJ-T1-GE3 |  SIA913DJ-T1-GE3 |  SIA914ADJ-T1-GE3 |  SIA914ADJ-T1-GE3 |  SIA914DJ-T1-GE3 |
|  SIA914DJ-T1-GE3 |  SIA915DJ-T1-GE3 |  SIA915DJ-T1-GE3 |  SIA917DJ-T1-GE3 |  SIA917DJ-T1-GE3 |

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